300 mA Adjustable Voltage **LDO Regulator**

Description

The CAT6220 is a 300 mA CMOS low dropout regulator whose output voltage is user adjustable that provides fast response time during load current and line voltage changes.

With 1 µA of shutdown current, an internal no-load operating current of only 10 µA, and full-load operating current of 40 µA, the CAT6220 is ideal for battery-operated devices with supply voltages from 2.3 V to 6.5 V.

The CAT6220 offers 1% initial accuracy and low dropout voltage, 270 mV typical at 300 mA. Stable operation is provided with a small value ceramic capacitor, reducing required board space and component cost.

Other features include current limit and thermal protection.

The device is available in the low profile (1 mm max height) 5-lead TSOT-23 and 6-pad 2 mm x 2 mm TDFN packages.

Features

- Guaranteed 300 mA Output Current
- Low Dropout Voltage of 270 mV at 300 mA
- Stable with Ceramic Output Capacitor
- No-load Ground Current of 10 µA Typical
- Full-load Ground Current of 40 µA Typical
- ±1.0% Output Voltage Initial Accuracy
- $\pm 2.0\%$ Accuracy over Temperature
- "Zero" Current Shutdown Mode
- Current Limit and Thermal Protection
- 5-lead TSOT-23 and 6-pad TDFN Packages
- EVICE IS OBSOL • These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- Toys
- Consumer Electronics
- Cellular Phones
- Battery-powered Devices



Figure 1. Typical Application Circuit



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TDFN-6 **VP5 SUFFIX** CASE 511AH

PIN CONNECTIONS



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 12 of this data sheet.

Table 1. PIN DESCRIPTIONS

	Package Pin #		
Pin Name	TSOT	TDFN	Function
VIN	1	3	Supply voltage input.
GND	2	2	Ground reference. All GND pins must be grounded.
EN	3	1	Enable input (active high)
ADJ	4	6	Digital programming input
NIC		5	No Internal Connection. A voltage or signal applied to this pin will have no effect upon device operation.
VOUT	5	4	Output Voltage Adjustment.
GND		PAD	Center pad or tab; for heat sinking

Pin Function

VIN is the supply pin for the LDO. A small 1 μ F ceramic bypass capacitor is required between the V_{IN} pin and ground near the device. When using longer connections to the power supply, C_{IN} value can be increased without limit. The operating input voltage range is from 2.3 V to 6.5 V.

EN is the enable control logic (active high) for the regulator output. Enable is a high impedance input and must not be left unconnected. Floating EN will result in unpredictable action at VOUT.

VOUT is the LDO regulator's output. Output voltage is set by two external resistors arranged as a voltage divider between VOUT and Ground. The center point of the divider is connected to ADJ as shown in Figure 2. The minimum recommended current through resistors is $5 \,\mu$ A. The ratio of the resistors is set by the formula:



Figure 2. R1 and R2 Set CAT6220's Output Voltage

A small 1 μ F ceramic bypass capacitor is required between the VOUT pin and ground. For better transient response, its value can be increased to 2.2 μ F. This capacitor should be located near the device.

GND is the ground reference for the LDO. This pin must be connected to the system ground line or the ground plane of the PCB.

The backside center pad of the TDFN package is internally connected to the GND pin. Any PCB connection to this pad must be either floating or at GND potential.

ADJ is the LDO's voltage control input. This pin is connected to the center of the resistor voltage divider R1, R2. A 10 pF capacitor connected in parallel with R1 will improve the transient load regulation for VOUT ≤ 2 V.

Thermal and Short Circuit Protection

CAT6220 is equipped with thermal protection and over-current limiting circuitry.

In the event of a short circuit CAT6220 will limit its output current to approximately 400 mA. If the short circuit persists CAT6220's internal temperature will rise and if the chip's temperature reaches 140°C CAT6220 will shut off all current to the load which protects the system and allows the LDO to cool down. When the LDO's internal temperature drops below 130°C the LDO automatically turns ON again. If the short circuit is still present another thermal cycle will ensue. This will continue until either the short circuit is removed or the Enable pin is taken LOW.

For the TSOT23–5 package, a continuous 300 mA output current may turn–on the thermal protection. If this happens the LDO will respond by shutting off power to the load and thermal cycling will begin.

Table 2. ABSOLUTE MAXIMUM RATINGS

Parameter	Rating	Unit
V _{IN}	0 to 7	V
V _{EN} , V _{OUT}	–0.3 to V _{IN} + 0.3	V
Junction Temperature, T _J	+150	°C
Power Dissipation, P _D	Internally Limited (Note 1)	mW
Storage Temperature Range, T _S	-65 to +150	°C
Lead Temperature (soldering, 5 sec.)	260	°C
ESD Rating (Human Body Model)	2	kV
ESD Rating (Machine Model)	200	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. The maximum allowable power dissipation at any T_A (ambient temperature) is $P_{Dmax} = (T_{Jmax} - T_A)/\theta_{JA}$. Exceeding the maximum allowable power dissipation will result in excessive die temperature, and the regulator will go into thermal shutdown.

Table 3. RECOMMENDED OPERATING CONDITIONS (Note 2)

Parameter	Range	Unit
V _{IN}	2.3 to 6.5	V
Гоцт	0.005 to 300	mA
V _{EN}	0 to V _{IN}	V
Junction Temperature Range, TJ	-40 to +140	°C
Package Thermal Resistance (TSOT23–5), θJA	280	°C/W
Package Thermal Resistance (TDFN–6), θ _{JA} The device is not guaranteed to work outside its operating rating.	160	°C/W

Table 4. ELECTRICAL OPERATING CHARACTERISTICS (Note 3) ($V_{IN} = V_{OUT} + 1.0 V$, $V_{EN} = High$, $I_{OUT} = 100 \mu A$, $C_{IN} = 1 \mu F$, $C_{OUT} = 1 \mu F$, ambient temperature of 25°C (over recommended operating conditions unless specified otherwise). **Bold numbers** apply for the entire junction temperature range.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{ADJ}	Adjustable Voltage	l _{OUT} = 100 μA		1.24		V
V _{ADJ}	Adjustable Voltage Accuracy	Initial accuracy	-1.5		+1.5	%
			-2.5		+2.5	
I _{ADJ}	ADJ pin Input Current			1	50	nA
TC _{OUT}	Output Voltage Temp. Coefficient			40		ppm/°C
V_{R-LINE}	Line Regulation	$V_{IN} = V_{OUT} + 1.0 V \text{ to } 6.5 V$	-0.2	±0.1	+0.2	%/V
			-0.35		+0.35	
V _{R-LOAD}	Load Regulation	I _{OUT} = 100 μA to 300 mA		0.9	1.5	%
					2.2	
V _{DROP}	Dropout Voltage (Note 4)	I _{OUT} = 300 mA		270	350	mV
					500	
I _{GND}	Ground Current	I _{OUT} = 5 μA		10	15	μΑ
				~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~	20	
		I _{OUT} = 300 mA		40	100	
I _{GND-SD}	Shutdown Ground Current	V _{EN} < 0.4 V			1	μΑ
			σ.	0	2	
PSRR	Power Supply Rejection Ratio	f = 100 Hz		62		dB
		f = 1 kHz	0.	48		
I _{SC}	Output short circuit current limit	V _{OUT} = 0 V		500	700	mA
T _{ON}	Turn–On Time			150		μs
e _N	Output Noise Voltage	BW = 10 Hz to 100 kHz, V _{OUT} = 1.8 V, I _{OUT} = 10 mA		150		μVrms
R _{OUT-SH}	Shutdown Switch Resistance			250		Ω
ESR	C _{OUT} equivalent series resistance		5		500	mΩ
DIGITAL IN	IPUT	~~~	-			

DIGITAL	INPUT
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V _{HI}	Logic High Level		V _{IN} = 2.3 to 6.5 V	1.8			V
		COL	V _{IN} = 2.3 to 6.5 V, 0°C to +125°C junction temperature	1.6			
V _{LO}	Logic Low Level		V _{IN} = 2.3 to 6.5 V			0.4	V
I _{IN}	Input Current	8	$V_{LOGIC} = 0.4 V$		0.15	1	μΑ
			$V_{LOGIC} = V_{IN}$		1.5	4	

THERMAL PROTECTION

T _{SD}	Thermal Shutdown		140	°C
T _{HYS}	Thermal Hysteresis		10	°C

3. Specification for 2.5 V output version unless specified otherwise.

4. Dropout voltage is defined as the input-to-output differential at which the output voltage drops 2% below its nominal value measured at 1 V differential. During test, the input voltage stays always above the minimum 2.3 V.









#### TRANSIENT CHARACTERISTICS



#### TRANSIENT CHARACTERISTICS



#### Table 5. THERMAL PERFORMANCE

Package	Symbol	Test Conditions	Min	Тур	Max	Unit
PACKAGE THERMAL CONDUCTIVITY COMPARISON						
TSOT-23-5	$\theta_{JA}$	1 oz Copper Thickness, 100 mm ²		280		°C/W
	θJC			68		
TDFN-6	$\theta_{JA}$	1 oz Copper Thickness, 100 mm ²		160		°C/W
	θJC			35		



Figure 27. Thermal Characteristic as a Function of Copper Area on the PCB

#### PACKAGE DIMENSIONS

TSOT-23, 5 LEAD CASE 419AE-01 ISSUE O



#### PACKAGE DIMENSIONS

**TDFN6**, 2x2 CASE 511AH-01 **ISSUE A** 



#### **ORDERING INFORMATION**

Device Order Number	Specific Device Marking	Package Type	Temperature Range	Lead Finish	Shipping (Note 7)
CAT6220TDI-GT3	X2	TSOT-23-5	I = Industrial (−40°C to +85°C)	NiPdAu	Tape & Reel, 3,000 Units / Reel
CAT6220VP5I-GT3	AK	TDFN–6	l = Industrial (-40°C to +85°C)	NiPdAu	Tape & Reel, 3,000 Units / Reel

5. All packages are RoHS-compliant (Lead-free, Halogen-free).

6. The standard lead finish is NiPdAu pre-plated (PPF) lead frames.

7. For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

8. For detailed information and a breakdown of device nomenclature and numbering systems, please see the ON Semiconductor Device Nomenclature document, TND310/D, available at <u>www.onsemi.com</u>

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